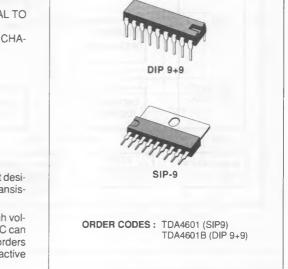


SWITCH-MODE POWER SUPPLY CONTROLLER

- LOW START-UP CURRENT
- DIRECT CONTROL OF SWITCHING TRANSIS-TOR
- COLLECTOR CURRENT PROPORTIONAL TO BASE-CURRENT INPUT
- REVERSE-GOING LINEAR OVERLOAD CHA-RACTERISTIC CURVE

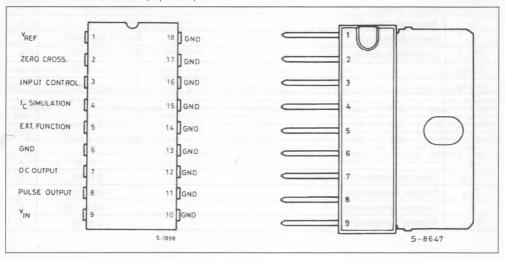


DESCRIPTION

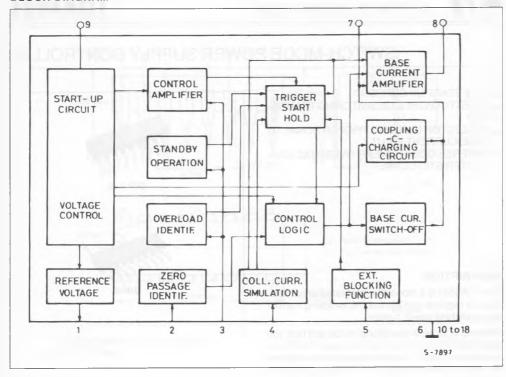
The TDA4601 is a monolithic integrated circuit designed to regulate and control the switching transistor a switching power supply.

Because of its wide operational range and high voltage stability even at high load changes: this IC can be used not only in TV receivers and video recorders but also in power supplies in Hi-Fi sets and active speakers.

CONNECTION DIAGRAM (top view)



BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V ₉	Supply Voltage	20	V
V ₁	Reference Output	6	V
V ₂	Identification Input	- 0.6 to 0.6	V
V ₃	Controlled Amplifier	3	V
V ₄ , V ₅		8	V
V ₇ , V ₈		V ₉	
l ₂ , l ₃		- 3 to 3	mA
14		5	mA
l ₅		5	mA
17		1.5	А
I ₈		- 1.5	A
Tamb	Operating Ambient Temperature	0 to 85	°C
T _{stq}	Storage Temperature	- 40 to 150	°C
Ti	Junction Temperature	- 40 to 125	°C
Tamb	Ambient Temperature	0 to 85	∞

THERMAL DATA

Rth j-case	Thermal Resistance Junction-pins	Max	15	°C/W
R _{th j-amb}	Thermal Resistance Junction-ambient	Max	70	°C/W

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V ₉	Operating Supply Voltage Range		7.8		18	V

START CONDITION (according to test circuit of fig. 1)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
l ₉	Supply Current (V ₁ not yet switched on)	$V_9 = 2 V V_9 = 5 V V_9 = 10 V$		1.5 2.4	0.5 2.0 3.2	mA mA
V ₉	Switch Threshold (V ₁)		11	11.8	12.3	V

NORMAL OPERATION (V $_{9}$ = 10 V, V $_{cont}$ = - 10 V, V $_{clock}$ = \pm 0.5 V, f = 20 KHz, duty cycle 1:2 after switch on)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
19	Supply Current	V _{cont} = - 10 V V _{cont} = 0 V	110 50	135 75	160 100	mA mA
V _{ref}	Voltage Reference at Pin 1	I ₁ < 0.1 mA I ₁ = 5 mA	4 4	4.2 4.2	4.5 4.4	V
V ₃	Control Voltage	V _{cont} = 0 V	2.3	2.6	2.9	V
V ₄	Collector Current Simulation Voltage	V _{cont} = 0 V	1.8	2.2	2.5	V
ΔV4	Collector Current Simulation Voltage	V _{cont} = 0 V to - 10 V	0.3	0.4	0.5	٧
V ₅	External Protection Threshold		6	7	8	V
V ₇	Pin 7 Output Voltage	V _{cont} = 0 V	2.7	3.3	4.0	V
V ₈	Pin 8 output Voltage	V _{cont} = 0 V	2.7	3.4	4.0	V
ΔV ₈	Pin 8 Output Voltage Change	V _{cont} 0 V to - 10 V	1.6	2	2.4	٧
V ₂	Feedback Voltage			0.2		٧
T _{K1}	Reference Voltage Temperature Coeffic.			10-3		1/K

PROTECTION OPERATION ($V_9 = 10 \text{ V}$; $V_{cont} = -10 \text{ V}$; $V_{clock} = \pm 0.5 \text{ V}$; f = 20 KHz; duty cycle 1:2)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
lg	Supply Current	V ₅ ≤ 1.8 V	14	22	28	mA
V ₇	Switch-off Voltage	V ₅ ≤ 1.8 V	1.3	1.5	1.8	V
V ₄			1.8	2.1	2.5	V

ELECTRICAL CHARACTERISTICS (continued)

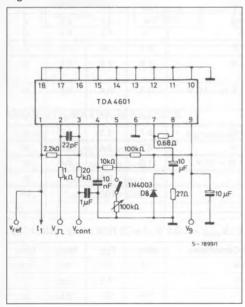
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V ₅		V _{cont} = 0 V	V	V ₁		V
			2 - 0.1	2		
V ₉	Supply Voltage for V ₈ Blocked	V _{cont} = 0 V	6.7	7.4	7.8	V
ΔV ₉	Supply Voltage for V ₁ off While Further Decreasing V ₉		0.3	0.6	1	V

ELECTRICAL CHARACTERISTICS (according to test circuit of fig. 2)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
ton	Secondary Voltage Switching Time			350	450	ms
ΔV2	Voltage Variation with Load	S ₃ Closed P ₃ = 20 W		0.1	0.5	٧
		S ₂ Closed P ₂ = 15 W		0.5	1	٧
ΔV ₂	Stand by Condition	S ₁ Open P _{load} = 3 W		20	30	٧
f	Stand by Frequency		70	75		KHz
P _P	Primary Power Consumption in Stand by Condition			10	12	VA

Note: 1) Only DC component.

Figure 1: Test Circuit.



Test Diagram: Overload Operation.

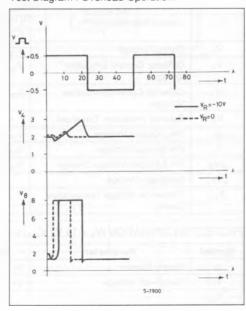
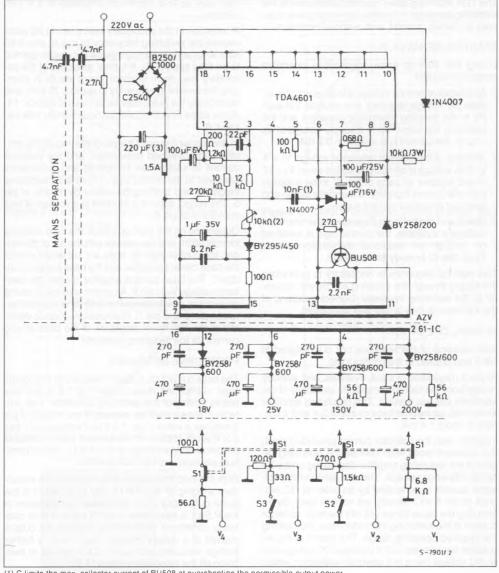


Figure 2: Test and Application Circuit.



- (1) C limits the max. collector current of BU508 at overshooting the permissible output power
- (2) Adjustement of secondary voltage
- (3) Must be discharged before IC change

CIRCUIT DESCRIPTION

The TDA 4601 regulates, controls, and protects the switching transistor in reverse converter power supplies at starting, normal, and overload operation.

STARTING BEHAVIOUR

During the start-up three consecutive operation states are passed.

- An internal reference voltage is built up which supplies the voltage regulator and enables the supply to the coupling electrolytic capacitor and the switching transistor. Up to a supply voltage of Vg ≈ 12 V, the current Ig is less than 3.2 mA.
- Release of the internal reference voltage V₁ = 4
 V. This voltage is abruptly available when V₂ ≈ 12
 V and enables all parts of the IC to be supplied from the control logic with a thermally stable and overload protected current supply.
- Release of control logic. As soon as the reference voltage is available, the control logic is switched on through an additional stabilization circuit. Thus, the IC is ready for operation.

This start-up sequence is necessary to guarantee the supply through the coupling electrolytic capacitor to the switching transistor. Correct switching of the transistor is only in this way guaranted.

NORMAL OPERATION

Zero crossing of the feedback coil is registered at pin 2 and passed to the control logic.

At pin 3 (regulation of input, overload, and standby recognition) the rectified amplitude variations of the feedback coil are applied. The regulating amplifier works with an input voltage of about 2 V and a current of about 1.4 mA.

Together with the collector current simulation pin 4, the overload recognition defines the operating region of the regulating amplifier depending on the internal reference voltage. The simulation of the collector current is generated by an external RC network at pin 4 an internally set voltage level. By increasing the capacitance (10 nF) the max. collector current of the switching transistor rises, thus setting the required operating range. The extent of the regulation lies between a 2 V clamped DC voltage and an AC voltage rising in a sawtooth waveform, which

may vary up to a maximum amplitude of 4 V (ref. voltage).

A reduction of the secondary load down to 20 watts causes the switching frequency to rise to about 50 KHz at an almost constant pulse duty factor (period to on-time approx. 3). A further reduction of the secondary load down to about 1 watt results in changing the switching frequency to approx. 70 KHz, and additionally the pulse duty factor rises to approx. 11. At the same time the collector peak current falls below 1 A.

In the trigger the output level of the regulating amplifier, the overload recognition, and the collector current simulation are compared and instructions are given to the control logic. There is an additional triggering and blocking possibility by means of pin 5. The output at pin 8 is blocked at a voltage of less than 2.2 V at pin 5.

Depending on the start-up circuit, the zero crossing identification, and the release with the aid of the trigger, the control logic flip flops are set which control the base current amplifier and the base current shutdown. The base current amplifier moves the sawtooth voltage V_4 to pin 8. A current feed-back having an external resistance of $R=0.68\,\Omega$ is inserted between pin 8 and pin 7. The resistance value determined the maximum amplitude of the base driving current for the switching transistor.

PROTECTIVE MEASURES

The base current shut-down, released by the control logic, clamps the output of pin 7 at 1.6 V and thus blocks driving of the switching transistor. This protective measure will be released if the voltage at pin 9 reaches a value \leq typ. 7.4 V or if voltages of \leq typ. 2.2 V occur at pin 5. In the case of a short circuit of the secondary windings of the P.S.U., the IC continuously monitors the fault condition.

With the load completely removed from the secondary winding of the P.S.U., the IC is set to a low pulse duty factor. The total power consumption of the P.S.U. is held below 6 to 10 watts in both operating conditions. After having blocked the output, caused at a supply voltage \leq typ. 7.4 V, a further voltage reduction with $\Delta V_9 = 0.6$ V results in switching off the reference voltage (4 V).

Figure 3: Frequency vs. Output Power (test circuit of fig. 2).

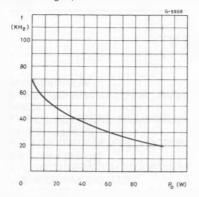


Figure 5 : Load Characteristics V₂-f (Iq2) (test circuit of fig. 2).

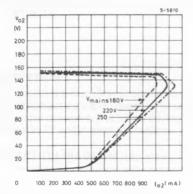


Figure 7: Example of a PC Heatsink (35 °C/W).

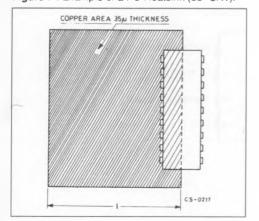


Figure 4: Efficiency vs. Output Power Test Circuit (of fig. 2).

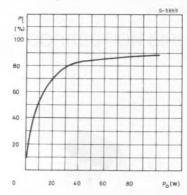


Figure 6: Output Voltage V₂ (mains change) (test circuit of fig. 2).

